



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
 United States Patent and Trademark Office
 Address: COMMISSIONER FOR PATENTS
 P.O. Box 1450
 Alexandria, Virginia 22313-1450
 www.uspto.gov

BIB DATA SHEET

CONFIRMATION NO. 8996

SERIAL NUMBER 10/530,562	FILING or 371(c) DATE 04/07/2005 RULE	CLASS 117	GROUP ART UNIT 1792	ATTORNEY DOCKET NO. Q87267		
APPLICANTS Masahiko Hata, Tsuchiura, JAPAN; ** CONTINUING DATA ***** This application is a 371 of PCT/JP03/13067 10/10/2003 ** FOREIGN APPLICATIONS ***** JAPAN 2002-301059 10/15/2002 ** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **						
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No 35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No Verified and /FELISA CARLA HITESHEW/ Acknowledged Examiner's Signature		<input type="checkbox"/> Met after Allowance STATE OR COUNTRY JAPAN	SHEETS DRAWINGS 1	TOTAL CLAIMS 14	INDEPENDENT CLAIMS 3	
ADDRESS SUGHRUE MION, PLLC 2100 PENNSYLVANIA AVENUE, N.W. SUITE 800 WASHINGTON, DC 20037 UNITED STATES						
TITLE Production method for thin-film crystal wafer, semiconductor device using it and production method therefor						
FILING FEE RECEIVED 1260	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit			